NSN 5961-01-452-8414

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-452-8414 **Inclosure Material:** Glass **Overall Length:** 80.770 millimeters **Terminal Length:** 4.570 millimeters **End Application:** Usaf f-16 mlu e/i fscm 81755 **Mounting Facility Quantity: Mounting Method: Terminal Terminal Circle Diameter:** 0.560 millimeters **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 150.0 breakdown voltage, dc and 125.0 working peak off-state voltage **Current Rating Per Characteristic:** 300.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 35.0 milliwatts small-signal input power, common-emitter absolute **Maximum Operating Tempurature Per Measurement Point:** -65.0 degrees celsius case and 175.0 degrees celsius case **Special Features:** Diode, silicon, switching **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-prf-19500/578 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0 Mil-std (military Standard):

Mil-prf-19500 spec.